

# LOW-VOLTAGE 10-BIT BUS SWITCH WITH PRECHARGED OUTPUTS

## IDT74CBTLV6800

# **FEATURES**:

- · Functionally equivalent to QS3800
- 5Ω A/B bi-directional switch
- · Isolation under power-off conditions
- · Over-voltage tolerant
- · Latch-up performance exceeds 100mA
- Vcc = 2.3V 3.6V, Normal Range
- ESD > 2000V per MIL-STD-883, Method 3015;
   > 200V using machine model (C = 200pF, R = 0)
- · Available in QSOP and TSSOP packages

### **APPLICATIONS:**

• 3.3V High Speed Bus Switching and Bus Isolation

### FUNCTIONAL BLOCK DIAGRAM

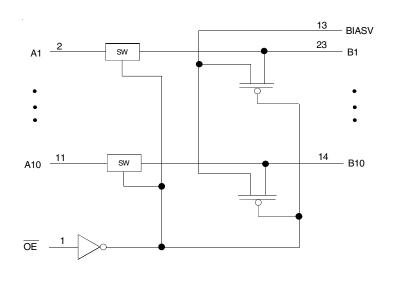
## **DESCRIPTION:**

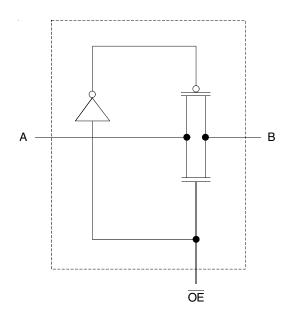
The CBTLV6800 provides 10-bits of high-speed bus switching with low on-state resistance of the switch allowing connections to be made with minimal propagation delay. The device also precharges the B port to a user-selectable bias voltage (BIASV) to minimize live-insertion noise.

The CBTLV6800 is organized as a single 10-bit bus switch with a single output-enable  $(\overline{OE})$  input. When  $\overline{OE}$  is low, the 10-bit bus switch is on and port A is connected to port B. When  $\overline{OE}$  is high, the switch is open, and a high impedance state exists between the two ports, and port B is precharged to BIASV through the equivalent of a 10-k $\Omega$  resistor.

To ensure the high-impedance state during power up or power down,  $\overline{\text{OE}}$  should be tied to VCC through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

# SIMPLIFIED SCHEMATIC, EACH SWITCH



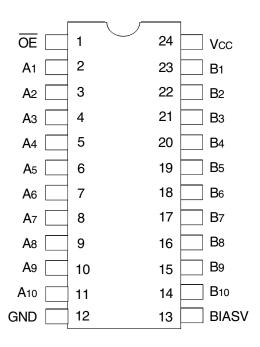


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INDUSTRIAL TEMPERATURE RANGE

JUNE 2006

## **PIN CONFIGURATION**



QSOP / TSSOP TOP VIEW

# ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
Vcc	SupplyVoltage Range	-0.5 to +4.6	
Vı	Input Voltage Range	-0.5 to +4.6	V
	Continuous Channel Current	128	mA
lik	Input Clamp Current, VI/O < 0	-50	mA
Tstg	Storage Temperature	-65 to +150	°C

### NOTE:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

# FUNCTION TABLE(1)

Input OE	Inputs/Outputs
L	A Port = B Port
Н	A Port = Z
	B Port = BIASV

### NOTE:

- 1. H = HIGH Voltage Level
- L = LOW Voltage Level
- Z = High-Impedance

# OPERATING CHARACTERISTICS, TA = 25°C(1)

Symbol	Parameter	Test Conditions	Min.	Мах.	Unit
Vcc	Supply Voltage		2.3	3.6	V
BIASV	Bias Voltage		1.3	Vcc	V
ViH	High-Level Control Input Voltage	Vcc = 2.3V to 2.7V	1.7	_	V
		Vcc = 2.7V to 3.6V	2	_	
VIL	Low-Level Control Input Voltage	Vcc = 2.3V to 2.7V	_	0.7	V
		Vcc = 2.7V to 3.6V	_	0.8	
TA	Operating Free-Air Temperature		-40	85	°C

#### NOTE:

1. All unused control inputs of the device must be held at Vcc or GND to ensure proper device operation.

# DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Conditions:  $TA = -40^{\circ}C$  to  $+85^{\circ}C$ 

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
Vik	Control Inputs, Data Inputs	Vcc = 3V, II = -18mA		_	_	-1.2	V
lı	Control Inputs	Vcc = 3.6V, VI = Vcc or GND		_	_	±1	μΑ
loz	Data I/O	Vcc = 3.6V, Vo = 0 or 3.6V, switch	n disabled	_	_	±20	μА
loff		Vcc = 0, Vi or Vo = 0 to 3.6V		_	_	50	μΑ
Io		Vcc = 3V, BIASV = 2.4V, Vo = 0	, $\overline{OE} = Vcc$	0.25	_	_	mA
Icc		Vcc = 3.6V, Io = 0, VI = Vcc or G	Vcc = 3.6V, Io = 0, VI = Vcc or GND		_	10	μΑ
<b>∆I</b> CC <sup>(1)</sup>	Control Inputs	Vcc = 3.6V, one input at 3V, other inputs at Vcc or GND		_	_	300	μА
Сі	Control Inputs	VI = 3V or 0		_	4	_	pF
CIO(OFF)		Vo = 3V or 0, switch OFF, BIASV = Open, $\overline{\sf OE}$ = Vcc		_	7	_	pF
	Vcc = 2.3V	VI = 0	lı = 64mA	_	5	8	
	Typ. at Vcc = 2.5V		lı = 24mA	_	5	8	
Ron <sup>(2)</sup>		VI = 1.7V	II = 15mA	_	27	40	Ω
		VI = 0	II = 64mA	_	5	7	
	Vcc = 3V		lı = 24mA	_	5	7	
		VI = 2.4V	II = 15mA	_	10	15	

#### NOTES:

## **SWITCHING CHARACTERISTICS**

		Vcc = 2.5V ± 0.2V		Vcc = 3.3V ± 0.3V		
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
<b>t</b> PD <sup>(1)</sup>	Propagation Delay	_	0.15	_	0.25	ns
	A to B or B to A					
tрzн	BIASV = 3V or GND	1	4.8	1	4.5	ns
<b>t</b> PZL	OE to A or B					
tрнz	BIASV = 3V or GND	1	5.6	1	5.5	ns
tplz	OE to A or B					

### NOTE:

<sup>1.</sup> The increase in supply current is attributable to each current that is at the specified voltage level rather than Vcc or GND.

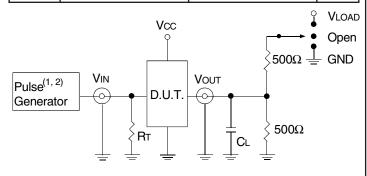
<sup>2.</sup> This is measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

<sup>1.</sup> The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance driven by an ideal voltage source (zero output impedance).

# TEST CIRCUITS AND WAVEFORMS

# **TEST CONDITIONS**

Symbol	$Vcc^{(1)} = 3.3V \pm 0.3V$	Vcc <sup>(2)</sup> = 2.5V±0.2V	Unit
VLOAD	6	2 x Vcc	V
VIH	3	Vcc	V
VT	1.5	Vcc / 2	V
VLZ	300	150	mV
VHZ	300	150	mV
CL	50	30	pF



Test Circuits for All Outputs

#### **DEFINITIONS:**

CL = Load capacitance: includes jig and probe capacitance.

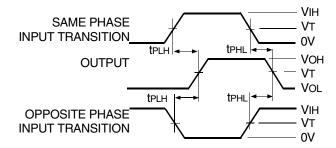
RT = Termination resistance: should be equal to ZouT of the Pulse Generator.

### NOTES:

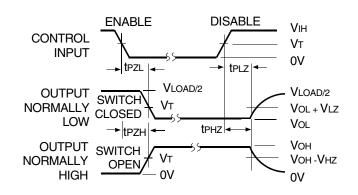
- 1. Pulse Generator for All Pulses: Rate  $\leq$  10MHz; tr  $\leq$  2.5ns; tr  $\leq$  2.5ns.
- 2. Pulse Generator for All Pulses: Rate  $\leq$  10MHz; tF  $\leq$  2ns; tR  $\leq$  2.5ns.

# **SWITCH POSITION**

Test	Switch
tplz/tpzl	Vload
tphz/tpzh	GND
teo	Open



### Propagation Delay



**Enable and Disable Times** 

# ORDERING INFORMATION

